BAV99 series

High-speed switching diodes Rev. 8 — 18 November 2010

Product data sheet

1. **Product profile**

1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number	Package	Package		Configuration	Package	
	NXP	JEITA	JEDEC		configuration	
BAV99	SOT23	'-	TO-236AB	dual series	small	
BAV99S	SOT363	SC-88	-	quadruple; 2 series	very small	
BAV99W	SOT323	SC-70	-	dual series	very small	

1.2 Features and benefits

- High switching speed: t_{rr} ≤ 4 ns
- Low leakage current
- Small SMD plastic packages
- Low capacitance: C_d ≤ 1.5 pF
- Reverse voltage: V_R ≤ 100 V
- AEC-Q101 qualified

1.3 Applications

- High-speed switching
- General-purpose switching
- Reverse polarity protection

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _R	reverse current	$V_{R} = 80 \ V$	-	-	0.5	μΑ
V_R	reverse voltage		-	-	100	V
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



2. Pinning information

Table 3. Pinning

Table 5.	ı ıııınıy		
Pin	Description	Simplified outline	Graphic symbol
BAV99; E	BAV99W		
1	anode (diode 1)		
2	cathode (diode 2)	3	3
3	cathode (diode 1), anode (diode 2)	1 2 006aaa144	
			006aaa763

BAV99S	3		
1	anode (diode 1)		
2	cathode (diode 2)	6 5 4	6 5 4
3	cathode (diode 3), anode (diode 4)	0	
4	anode (diode 3)	1 2 3	
5	cathode (diode 4)		1 2 3
6	cathode (diode 1), anode (diode 2)		006aab101

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
BAV99	-	plastic surface-mounted package; 3 leads	SOT23
BAV99S	SC-88	plastic surface-mounted package; 6 leads	SOT363
BAV99W	SC-70	plastic surface-mounted package; 3 leads	SOT323

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
BAV99	A7*
BAV99S	K1*
BAV99W	A7*

[1] * = placeholder for manufacturing site code

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	100	V
I _F	forward current				
	BAV99		[1] -	215	mA
			[2] _	125	mA
	BAV99S		<u>[1]</u> -	200	mA
	BAV99W		<u>[1]</u> -	150	mA
			[2] -	130	mA
I _{FRM}	repetitive peak forward current		-	500	mA
I _{FSM}	non-repetitive peak forward current	square wave	<u>[3]</u>		
		t _p = 1 μs	-	4	А
		$t_p = 1 \text{ ms}$	-	1	Α
		t _p = 1 s	-	0.5	Α
P _{tot}	total power dissipation		<u>[1][4]</u>		
	BAV99	$T_{amb} \le 25 ^{\circ}C$	-	250	mW
	BAV99S	$T_{sp} \le 85 ^{\circ}C$	<u>[5]</u> _	250	mW
	BAV99W	$T_{amb} \le 25 ^{\circ}C$	-	200	mW
Per device					
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Single diode loaded.

^[2] Double diode loaded.

^[3] $T_i = 25$ °C prior to surge.

^[4] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[5] Soldering points at pins 2, 3, 5 and 6.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]			
	BAV99		-	-	500	K/W
	BAV99W		-	-	625	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point					
	BAV99		-	-	360	K/W
	BAV99S		<u>[3]</u> _	-	260	K/W
	BAV99W		-	-	300	K/W

^[1] Single diode loaded.

7. Characteristics

Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

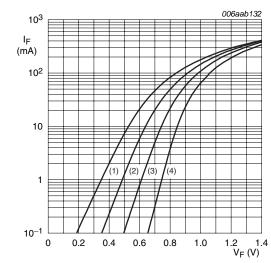
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	9					
V_{F}	forward voltage	I _F = 1 mA	-	-	715	mV
		I _F = 10 mA	-	-	855	mV
	$I_F = 50 \text{ mA}$	-	-	1	V	
		I _F = 150 mA	-	-	1.25	V
I_R	reverse current	V _R = 25 V	-	-	30	nA
		V _R = 80 V	-	-	0.5	μΑ
		$V_R = 25 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	30	μΑ
		$V_R = 80 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns
V_{FR}	forward recovery voltage		[2] _	-	1.75	V

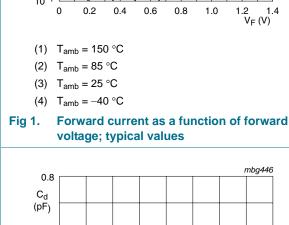
^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 $\Omega;$ measured at I_R = 1 mA.

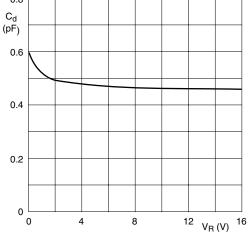
^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Soldering points at pins 2, 3, 5 and 6.

^[2] When switched from $I_F = 10$ mA; $t_r = 20$ ns.

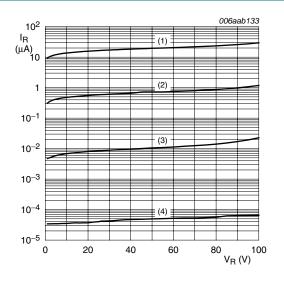






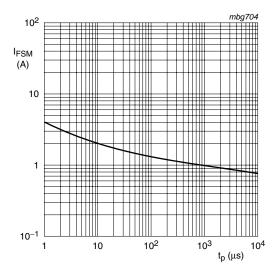
 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

Reverse current as a function of reverse Fig 2. voltage; typical values

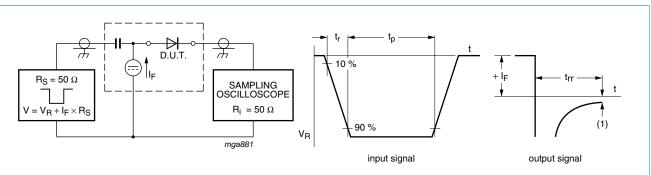


Based on square wave currents.

T_i = 25 °C; prior to surge

Fig 4. Non-repetitive peak forward current as a function of pulse duration; maximum values

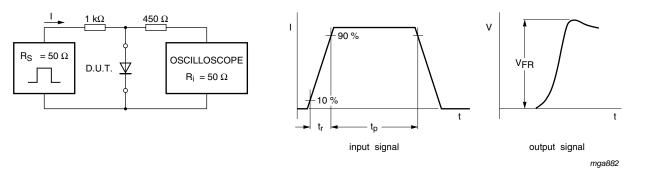
8. Test information



(1) $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty cycle δ = 0.05 Oscilloscope: rise time t_r = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



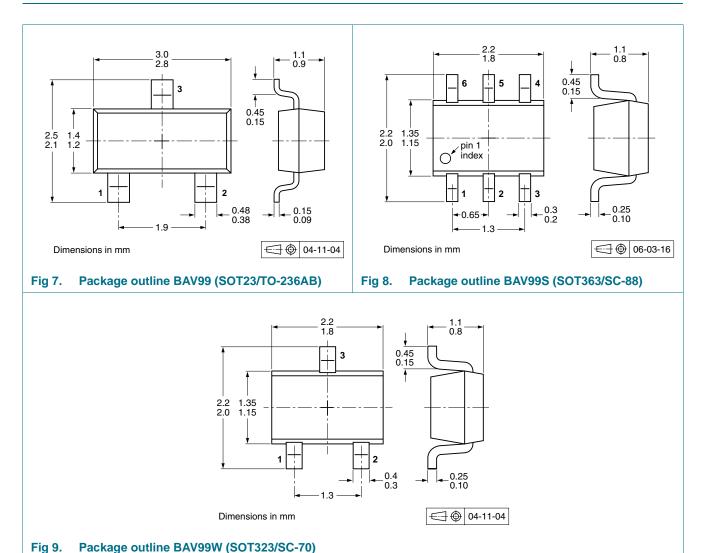
Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

Fig 6. Forward recovery voltage test circuit and waveforms

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Type number Package Description		Packing quantity		
			3000	10000	
BAV99	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	
BAV99S	SOT363	4 mm pitch, 8 mm tape and reel; T1	-115	-135	
		4 mm pitch, 8 mm tape and reel; T2	-125	-165	
BAV99W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135	

[1] For further information and the availability of packing methods, see Section 14.

[2] T1: normal taping

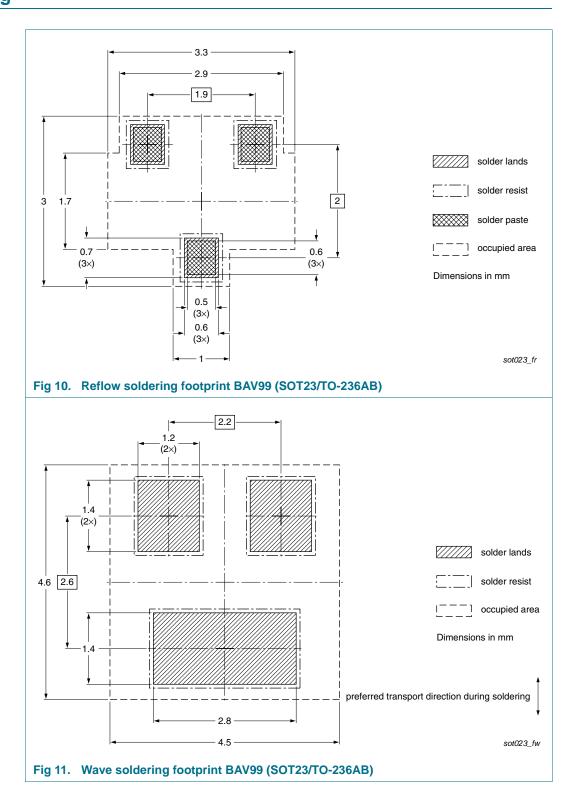
[3] T2: reverse taping

BAV99 SER

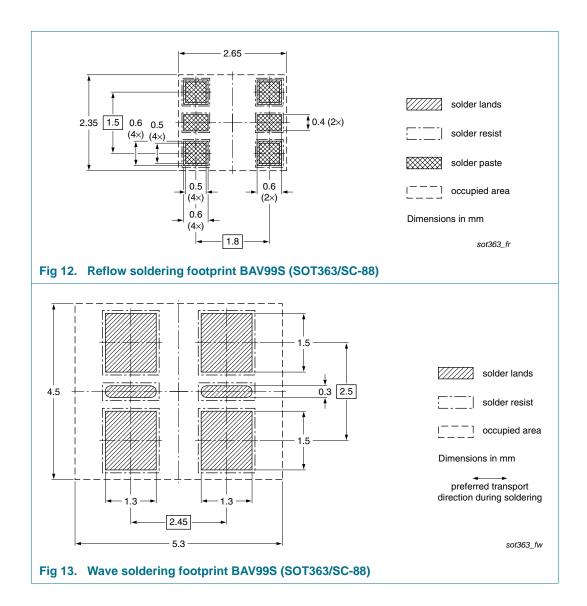
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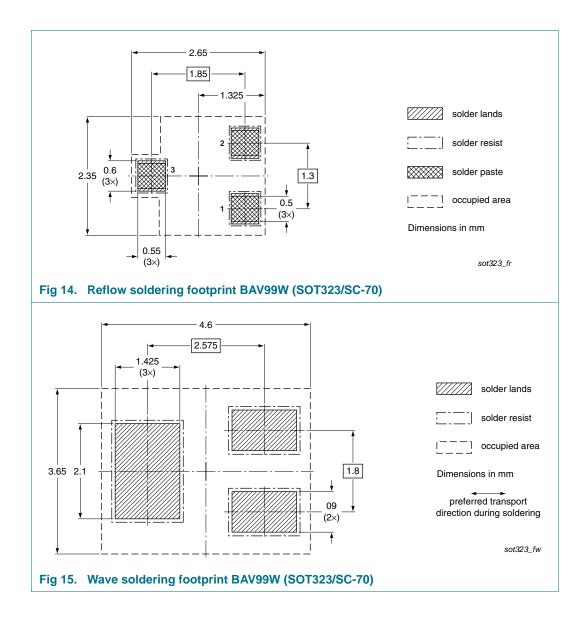
11. Soldering



High-speed switching diodes



High-speed switching diodes



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12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAV99_SER_8	20101118	Product data sheet	-	BAV99_SER_7
Modifications:	 Section 4 "M 	arking": marking placeholder e	explanation in table for	ooter updated
	 Section 5 "Li 	miting values": Ptot condition for	or BAV99S corrected	
	 Section 13 "L 	<u>egal information</u> ": updated		
BAV99_SER_7	20100414	Product data sheet	-	BAV99_SER_6
BAV99_SER_6	20100310	Product data sheet	-	BAV99_SER_5
BAV99_SER_5	20080820	Product data sheet	-	BAV99_4
				BAV99S_3 BAV99W 4
BAV99_4	20011015	Product specification	-	BAV99_3
BAV99S_3	20010514	Product specification	-	BAV99S_N_2
BAV99W_4	19990511	Product specification	-	BAV99W_3

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAV99 series

High-speed switching diodes

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BAV99 series

High-speed switching diodes

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